TinyLogic UHS Dual Unbuffered Inverter

NC7WZU04

ON Semiconductor®

www.onsemi.com

Description

The NC7WZU04 is a dual unbuffered inverter from ON Semiconductor's Ultra High Speed Series of TinyLogic in the space saving SC−88 6−lead package. The special purpose unbuffered circuit design is intended for crystal oscillator or analog applications. The internal circuit consists of only one−stage, the output, to allow for this part to be used in these oscillator or analog applications. The device is fabricated with advanced CMOS technology to achieve ultra high speed with high output drive while maintaining low static power dissipation over a very broad V_{CC} operating range. The device is specified to operate over the 1.65 V to 5.5 V V_{CC} range. The inputs are high impedance when V_{CC} is 0 V. Inputs tolerate voltages up to 5.5 V independent of V_{CC} operating voltage.

Features

- Space−Saving SC−88 6−Lead Package
- Ultra−Small MicroPak™ Leadless Packages
- Unbuffered for Crystal Oscillator and Analog Applications
- Balanced Output Drive: ±32 mA at 4.5 V V_{CC}
- Broad V_{CC} Operating Range: 1.65 V to 5.5 V
- Low Quiescent Power: I_{CC} < 1 μA at 5 V V_{CC}, T_A = 25°C
- These Devices are Pb−Free, Halogen Free/BFR Free and are RoHS Compliant

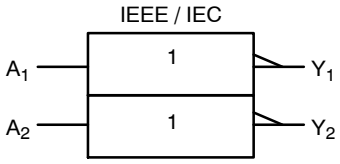
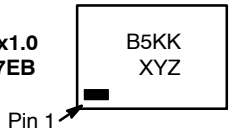
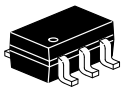


Figure 1. Logic Symbol

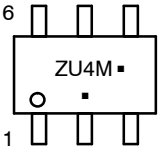
MARKING DIAGRAMS

SIP6 1.45x1.0
CASE 127EB





SC−88
CASE 419B−02



B5, ZU4	= Specific Device Code
KK	= 2−Digit Lot Run Traceability Code
XY	= 2−Digit Date Code Format
Z	= Assembly Plant Code
M	= Data Code*
▪	= Pb−Free Package

(Note: Microdot may be in either location)

*Date Code orientation and/or position may vary depending upon manufacturing location.

ORDERING INFORMATION

See detailed ordering, marking and shipping information in the package dimensions section on page 6 of this data sheet.

Pin Configurations

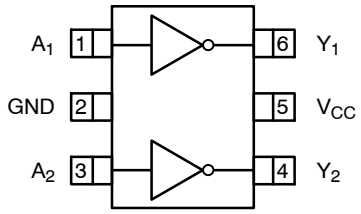


Figure 2. SC−88 (Top View)

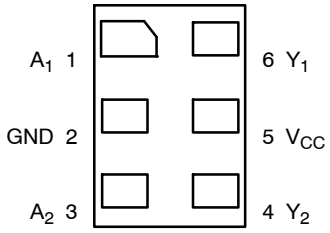
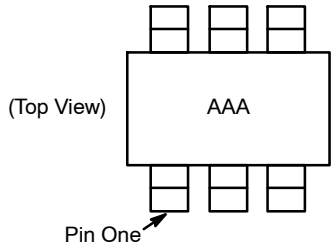


Figure 3. MicroPak (Top Through View)



AAA represents Product Code Top Mark − see ordering code

NOTE: Orientation of Top Mark determines Pin One location. Reading the top product code mark left to right, Pin One is the lower left pin (see diagram).

Figure 4. SC−88 Pin 1 Orientation

PIN DEFINITIONS

Pin Name	Description
A_1, A_2	Data Inputs
Y_1, Y_2	Outputs

FUNCTION TABLE ($Y = \overline{A}$)

Input	Output
A	**Y**
L	H
H	L

H = HIGH Logic Level
L = LOW Logic Level

ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter		Min	Max	Unit
V_{CC}	Supply Voltage		−0.5	6.5	V
V_{IN}	DC Input Voltage		−0.5	6.5	V
V_{OUT}	DC Output Voltage		−0.5	V_{CC} + 0.5	V
I_{IK}	DC Input Diode Current	V_{IN} < 0 V	−	−50	mA
I_{OK}	DC Output Diode Current	V_{OUT} < 0 V	−	−50	mA
		V_{OUT} > V_{CC}	−	+50	mA
I_{OUT}	DC Output Current		−	±50	mA
I_{CC} or I_{GND}	DC V_{CC} / GND Current		−	±50	mA
T_{STG}	Storage Temperature		−65	+150	°C
T_J	Junction Temperature Under Bias		−	150	°C
T_L	Junction Lead Temperature (Soldering, 10 Seconds)		−	260	°C
P_D	Power Dissipation in Still Air	SC−88	−	332	mW
		MicroPak−6	−	812	

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Conditions	Min	Max	Unit
V_{CC}	Supply Voltage Operating		1.65	5.5	V
	Supply Voltage Data Retention		1.5	5.5	
V_{IN}	Input Voltage		0	5.5	V
V_{OUT}	Output Voltage		0	V_{CC}	V
T_A	Operating Temperature		−40	+85	°C
θ_{JA}	Thermal Resistance	SC−88	−	377	°C/W
		MicroPak−6	−	154	

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

1. Unused inputs must be held HIGH or LOW. They may not float.

DC ELECTICAL CHARACTERISTICS

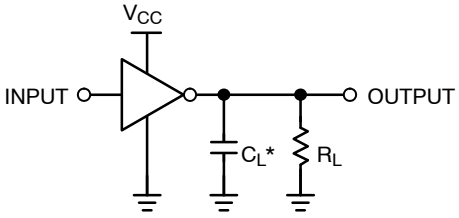
Symbol	Parameter	Conditions	V_{CC} (V)	T_A = +25°C			T_A = −40 to +85°C		Unit
				Min	Typ	Max	Min	Max	
V_{IH}	HIGH Level Input Voltage		1.8 to 2.7	0.85 V_{CC}	–	–	0.85 V_{CC}	–	V
			3.0 to 5.5	0.8 V_{CC}	–	–	0.8 V_{CC}	–	
V_{IL}	LOW Level Input Voltage		1.8 to 2.7	–	–	0.15 V_{CC}	–	0.15 V_{CC}	V
			3.0 to 5.5	–	–	0.2 V_{CC}	–	0.2 V_{CC}	
V_{OH}	High−Level Output Voltage	V_{IN} = GND I_{OH} = −100 μA I_{OH} = −4 mA I_{OH} = −8 mA I_{OH} = −12 mA I_{OH} = −16 mA I_{OH} = −24 mA I_{OH} = −32 mA	 1.65 to 5.5 1.65 2.3 2.7 3.0 3.0 4.5	 V_{CC} − 0.1 1.29 1.9 2.2 2.4 2.3 3.8	 V_{CC} 1.4 2.1 2.4 2.7 2.5 4.0	 – – – – – – –	 V_{CC} − 0.1 1.29 1.9 2.2 2.4 2.3 3.8	 – – – – – – –	V
V_{OL}	Low−Level Output Voltage	V_{IN} = V_{CC} I_{OL} = 100 μA I_{OL} = 4 mA I_{OL} = 8 mA I_{OL} = 12 mA I_{OL} = 16 mA I_{OL} = 24 mA I_{OL} = 32 mA	 1.65 to 5.5 1.65 2.3 2.7 3.0 3.0 4.5	 – – – – – – – –	 – 0.08 0.2 0.22 0.28 0.38 0.42	 0.1 0.24 0.3 0.4 0.4 0.55 0.55	 – – – – – – –	 0.1 0.24 0.3 0.4 0.4 0.55 0.55	V
I_{IN}	Input Leakage Current	V_{IN} = 5.5 V, GND	1.65 to 5.5	–	–	±0.1	–	±1.0	μA
I_{CC}	Quiescent Supply Current	V_{IN} = 5.5 V, GND	1.65 to 5.5	–	–	1.0	–	10	μA
I_{CCPEAK}	Peak Supply Current in Analog Operation	V_{OUT} = Open V_{IN} = Adjust for Peak I_{CC} Current	1.8	–	0.2	–	–	–	mA
			2.5	–	2	–	–	–	
			3.3	–	5	–	–	–	
			5.0	–	15	–	–	–	

AC ELECTRICAL CHARACTERISTICS

Symbol	Parameter	V_{CC} (V)	Conditions	T_A = +25°C			T_A = −40 to +85°C		Unit
				Min	Typ	Max	Min	Max	
t_{PLH}, t_{PHL}	Propagation Delay (Figure 5, 6)	1.65	C_L = 15 pF, R_L = 1 MΩ	–	5.5	9.8	–	11.0	ns
		1.8		–	4.6	8.1	–	8.9	
		2.5 ±0.2		–	3.3	5.7	–	6.3	
		3.3 ±0.3		–	2.7	4.1	–	4.5	
		5.0 ±0.5		–	2.2	3.3	–	3.6	
		3.3 ±0.3	C_L = 50 pF, R_L = 500 Ω	–	4.0	6.4	–	7.0	
		5.0 ±0.5		–	3.4	5.6	–	6.2	
C_{IN}	Input Capacitance	0		–	3	–	–	–	pF
C_{PD}	Power Dissipation Capacitance (Figure 7)	3.3	(Note 2)	–	3.5	–	–	–	pF
		5.0		–	5.5	–	–	–	

2. C_{PD} is defined as the value of the internal equivalent capacitance which is derived from dynamic operating current consumption (I_{CCD}) at no output loading and operating at 50% duty cycle. C_{PD} is related to I_{CCD} dynamic operating current by the expression: $I_{CCD} = (C_{PD})\ (V_{CC})\ (f_{IN}) + (I_{CC}static)$.

AC Loading and Waveforms



*C_L includes load and stray capacitance.
Input PRR = 1.0 MHz, t_W = 500 ns.

Figure 5. AC Test Circuit

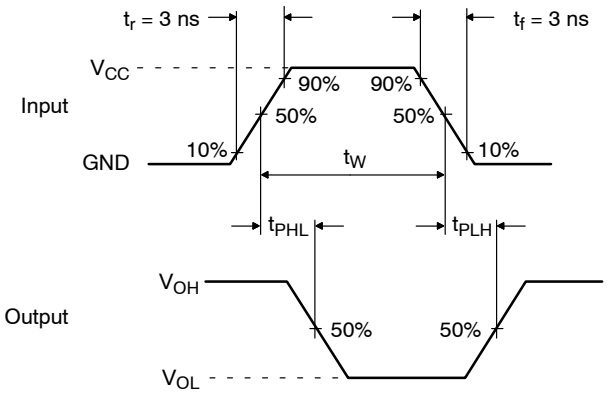
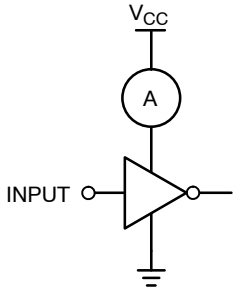


Figure 6. AC Waveforms



Application Note: When operating the NC7WZU04's unbuffered output stage in its linear range, as in oscillator applications, care must be taken to observe maximum power rating for the device and package. The high drive nature of the design of the output stage will result in substantial simultaneous conduction currents when the stage is in the linear region. See the I_{CCPEAK} specification on page 4.

Input = AC Waveform; $t_r = t_f$ = 1.8 ns.
PRR = 10 MHz; Duty Cycle = 50%.

Figure 7. I_{CCD} Test Circuit

DEVICE ORDERING INFORMATION

Device	Top Mark	Packages	Shipping†
NC7WZU04P6X	ZU4	SC−88	3000 / Tape & Reel
NC7WZU04L6X	B5	MicroPak	5000 / Tape & Reel

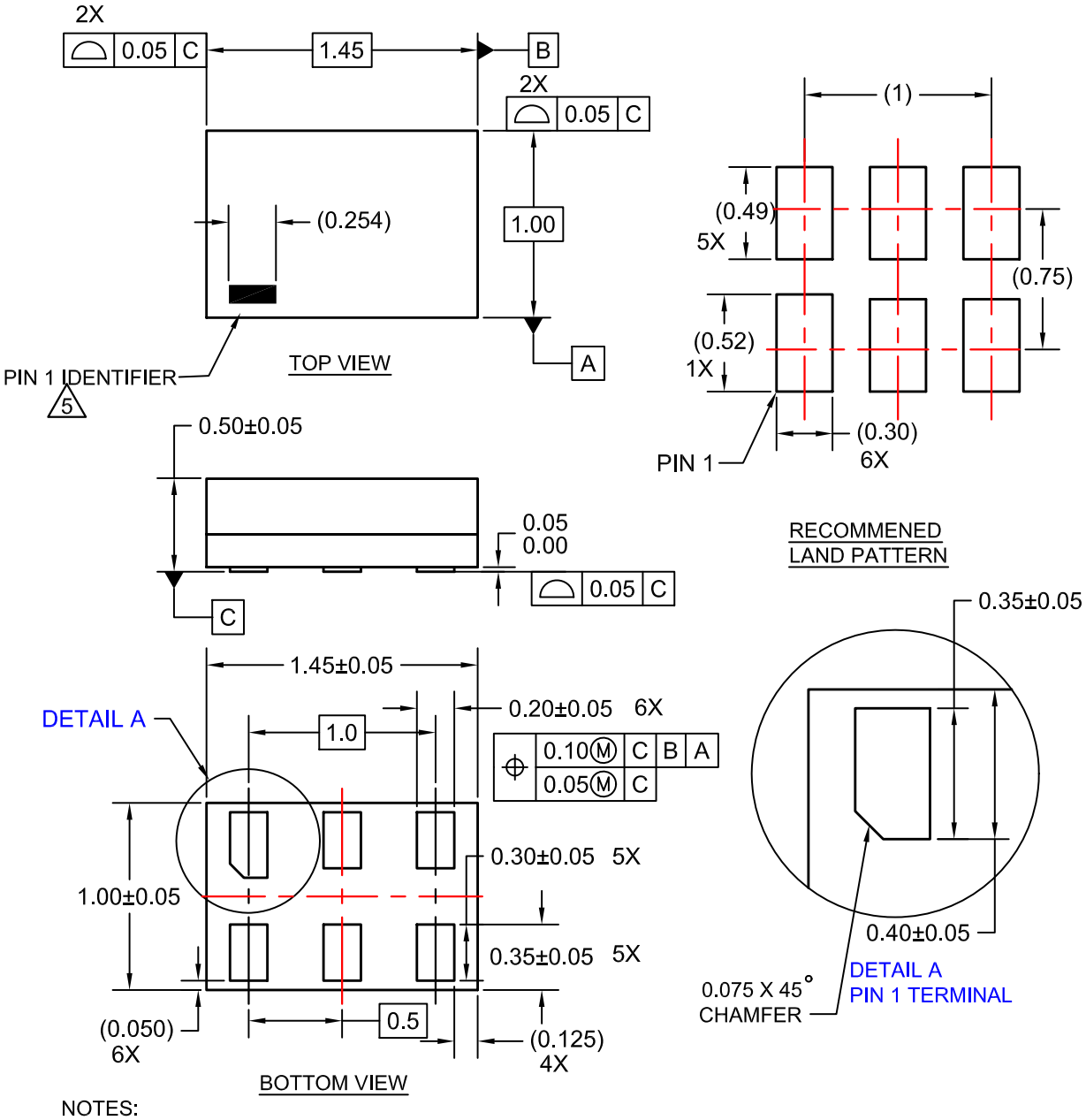
†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

MECHANICAL CASE OUTLINE
PACKAGE DIMENSIONS

ON Semiconductor®

SIP6 1.45X1.0
CASE 127EB
ISSUE O

DATE 31 AUG 2016



NOTES:

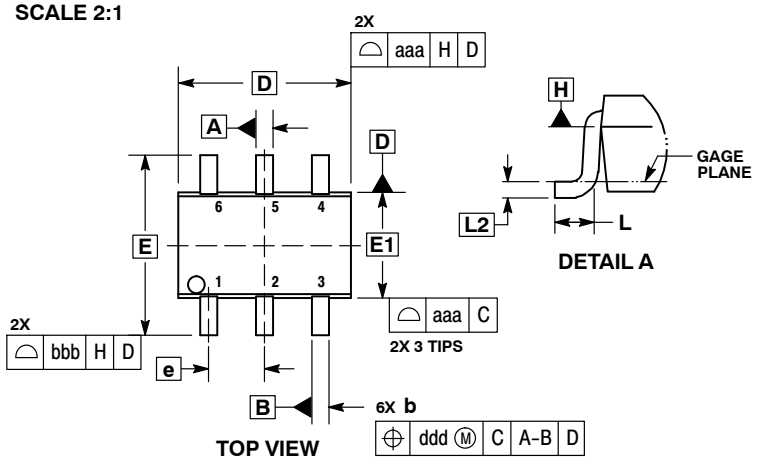
1. CONFORMS TO JEDEC STANDARD MO-252 VARIATION UAAD
2. DIMENSIONS ARE IN MILLIMETERS
3. DRAWING CONFORMS TO ASME Y14.5M-2009
4. PIN ONE IDENTIFIER IS 2X LENGTH OF ANY OTHER LINE IN THE MARK CODE LAYOUT.

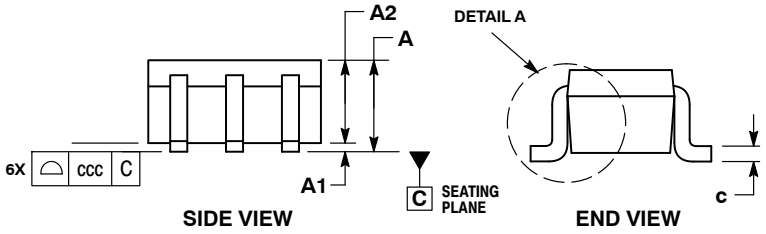
DOCUMENT NUMBER:	**98AON13590G**	Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.
DESCRIPTION:	**SIP6 1.45X1.0**	**PAGE 1 OF 1**

SC−88/SC70−6/SOT−363
CASE 419B−02
ISSUE Y

DATE 11 DEC 2012

1
SCALE 2:1

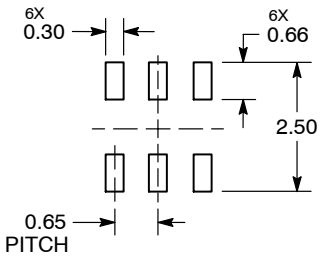




NOTES:
1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: MILLIMETERS.
3. DIMENSIONS D AND E1 DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS. MOLD FLASH, PROTRUSIONS, OR GATE BURRS SHALL NOT EXCEED 0.20 PER END.
4. DIMENSIONS D AND E1 AT THE OUTERMOST EXTREMES OF THE PLASTIC BODY AND DATUM H.
5. DATUMS A AND B ARE DETERMINED AT DATUM H.
6. DIMENSIONS b AND c APPLY TO THE FLAT SECTION OF THE LEAD BETWEEN 0.08 AND 0.15 FROM THE TIP.
7. DIMENSION b DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 TOTAL IN EXCESS OF DIMENSION b AT MAXIMUM MATERIAL CONDITION. THE DAMBAR CANNOT BE LOCATED ON THE LOWER RADIUS OF THE FOOT.

	MILLIMETERS			INCHES		
DIM	**MIN**	**NOM**	**MAX**	**MIN**	**NOM**	**MAX**
A	−−−	−−−	1.10	−−−	−−−	0.043
A1	0.00	−−−	0.10	0.000	−−−	0.004
A2	0.70	0.90	1.00	0.027	0.035	0.039
b	0.15	0.20	0.25	0.006	0.008	0.010
C	0.08	0.15	0.22	0.003	0.006	0.009
D	1.80	2.00	2.20	0.070	0.078	0.086
E	2.00	2.10	2.20	0.078	0.082	0.086
E1	1.15	1.25	1.35	0.045	0.049	0.053
e	0.65 BSC			0.026 BSC		
L	0.26	0.36	0.46	0.010	0.014	0.018
L2	0.15 BSC			0.006 BSC		
aaa	0.15			0.006		
bbb	0.30			0.012		
ccc	0.10			0.004		
ddd	0.10			0.004		

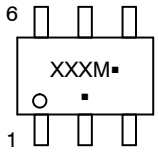
RECOMMENDED SOLDERING FOOTPRINT*



DIMENSIONS: MILLIMETERS

*For additional information on our Pb−Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

GENERIC MARKING DIAGRAM*



XXX = Specific Device Code
M = Date Code*
▪ = Pb−Free Package

(Note: Microdot may be in either location)

*Date Code orientation and/or position may vary depending upon manufacturing location.

*This information is generic. Please refer to device data sheet for actual part marking. Pb−Free indicator, “G” or microdot “▪”, may or may not be present. Some products may not follow the Generic Marking.

STYLES ON PAGE 2

SC−88/SC70−6/SOT−363
CASE 419B−02
ISSUE Y

DATE 11 DEC 2012

STYLE 1:
PIN 1. EMITTER 2
2. BASE 2
3. COLLECTOR 1
4. EMITTER 1
5. BASE 1
6. COLLECTOR 2

STYLE 2:
CANCELLED

STYLE 3:
CANCELLED

STYLE 4:
PIN 1. CATHODE
2. CATHODE
3. COLLECTOR
4. EMITTER
5. BASE
6. ANODE

STYLE 5:
PIN 1. ANODE
2. ANODE
3. COLLECTOR
4. EMITTER
5. BASE
6. CATHODE

STYLE 6:
PIN 1. ANODE 2
2. N/C
3. CATHODE 1
4. ANODE 1
5. N/C
6. CATHODE 2

STYLE 7:
PIN 1. SOURCE 2
2. DRAIN 2
3. GATE 1
4. SOURCE 1
5. DRAIN 1
6. GATE 2

STYLE 8:
CANCELLED

STYLE 9:
PIN 1. EMITTER 2
2. EMITTER 1
3. COLLECTOR 1
4. BASE 1
5. BASE 2
6. COLLECTOR 2

STYLE 10:
PIN 1. SOURCE 2
2. SOURCE 1
3. GATE 1
4. DRAIN 1
5. DRAIN 2
6. GATE 2

STYLE 11:
PIN 1. CATHODE 2
2. CATHODE 2
3. ANODE 1
4. CATHODE 1
5. CATHODE 1
6. ANODE 2

STYLE 12:
PIN 1. ANODE 2
2. ANODE 2
3. CATHODE 1
4. ANODE 1
5. ANODE 1
6. CATHODE 2

STYLE 13:
PIN 1. ANODE
2. N/C
3. COLLECTOR
4. EMITTER
5. BASE
6. CATHODE

STYLE 14:
PIN 1. VREF
2. GND
3. GND
4. IOUT
5. VEN
6. VCC

STYLE 15:
PIN 1. ANODE 1
2. ANODE 2
3. ANODE 3
4. CATHODE 3
5. CATHODE 2
6. CATHODE 1

STYLE 16:
PIN 1. BASE 1
2. EMITTER 2
3. COLLECTOR 2
4. BASE 2
5. EMITTER 1
6. COLLECTOR 1

STYLE 17:
PIN 1. BASE 1
2. EMITTER 1
3. COLLECTOR 2
4. BASE 2
5. EMITTER 2
6. COLLECTOR 1

STYLE 18:
PIN 1. VIN1
2. VCC
3. VOUT2
4. VIN2
5. GND
6. VOUT1

STYLE 19:
PIN 1. I OUT
2. GND
3. GND
4. V CC
5. V EN
6. V REF

STYLE 20:
PIN 1. COLLECTOR
2. COLLECTOR
3. BASE
4. EMITTER
5. COLLECTOR
6. COLLECTOR

STYLE 21:
PIN 1. ANODE 1
2. N/C
3. ANODE 2
4. CATHODE 2
5. N/C
6. CATHODE 1

STYLE 22:
PIN 1. D1 (i)
2. GND
3. D2 (i)
4. D2 (c)
5. VBUS
6. D1 (c)

STYLE 23:
PIN 1. Vn
2. CH1
3. Vp
4. N/C
5. CH2
6. N/C

STYLE 24:
PIN 1. CATHODE
2. ANODE
3. CATHODE
4. CATHODE
5. CATHODE
6. CATHODE

STYLE 25:
PIN 1. BASE 1
2. CATHODE
3. COLLECTOR 2
4. BASE 2
5. EMITTER
6. COLLECTOR 1

STYLE 26:
PIN 1. SOURCE 1
2. GATE 1
3. DRAIN 2
4. SOURCE 2
5. GATE 2
6. DRAIN 1

STYLE 27:
PIN 1. BASE 2
2. BASE 1
3. COLLECTOR 1
4. EMITTER 1
5. EMITTER 2
6. COLLECTOR 2

STYLE 28:
PIN 1. DRAIN
2. DRAIN
3. GATE
4. SOURCE
5. DRAIN
6. DRAIN

STYLE 29:
PIN 1. ANODE
2. ANODE
3. COLLECTOR
4. EMITTER
5. BASE/ANODE
6. CATHODE

STYLE 30:
PIN 1. SOURCE 1
2. DRAIN 2
3. DRAIN 2
4. SOURCE 2
5. GATE 1
6. DRAIN 1

Note: Please refer to datasheet for style callout. If style type is not called out in the datasheet refer to the device datasheet pinout or pin assignment.

DOCUMENT NUMBER:	**98ASB42985B**	Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.
DESCRIPTION:	**SC−88/SC70−6/SOT−363**	**PAGE 2 OF 2**

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:
Email Requests to: orderlit@onsemi.com

onsemi Website: www.onsemi.com

TECHNICAL SUPPORT
North American Technical Support:
Voice Mail: 1 800−282−9855 Toll Free USA/Canada
Phone: 011 421 33 790 2910

Europe, Middle East and Africa Technical Support:
Phone: 00421 33 790 2910
For additional information, please contact your local Sales Representative

◊

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for Inverters ***category:***

Click to view products by ON Semiconductor ***manufacturer:***

Other Similar products are found below :

E5-652Z NL17SGU04P5T5G NLX2G04BMX1TCG CD4009UBE TC4584BFN 022413E NL17SG14AMUTCG NLU2G04AMUTCG NLU2GU04BMX1TCG NLU2G04CMX1TCG NLV17SZ06DFT2G TC74VHC04FK(EL,K) NLV74HC04ADTR2G NLU1G04AMUTCG NLX2G04CMUTCG NLX2G04AMUTCG NLU1GU04CMUTCG NLU1GT14AMUTCG NLU1G04CMUTCG NL17SZU04P5T5G 74LVC06ADTR2G 74LVC04ADR2G NLV37WZ04USG NLX3G14FMUTCG NL17SZ04P5T5G NLV17SG14DFT2G 74ACT14SC BU4069UBF-E2 EMPP008Z NC7WZ14P6X NLV14106BDTR2G NLV74AC14DTR2G SN74HCT04DE4 ODE-3-120023-1F12 74VHCT04AM SV004IE5-1C TC74HC04APF TC7SH04F,LJ(CT TC7W14FK,LF 74VHC14MTCX 74LCX14MTC SN74LVC1GU04DBVR NLU1G14BMX1TCG NLU2G04AMX1TCG NLU2G14AMX1TCG NLU3G14AMX1TCG NLVVHC1G04DFT2G NLX2G04CMX1TCG NLX3G14AMX1TCG 74HC14T14-13